

## Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200 V Forward Current - 3 A

### FEATURES

- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

### MECHANICAL DATA

- Case: SMC
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.22g / 0.0077oz

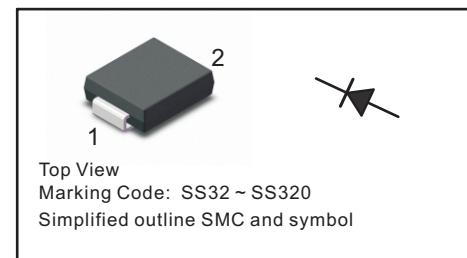
### Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

### PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Parameter	Symbols	SS32C G	SS34C G	SS36C G	SS38C G	SS310C G	SS312C G	SS315C G	SS320C G	Units		
Maximum Repetitive Peak Reverse Voltage	V <sub>RRM</sub>	20	40	60	80	100	120	150	200	V		
Maximum RMS voltage	V <sub>RMS</sub>	14	28	42	56	70	84	105	140	V		
Maximum DC Blocking Voltage	V <sub>DC</sub>	20	40	60	80	100	120	150	200	V		
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>	3.0							A			
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	80							A			
Max Instantaneous Forward Voltage at 3 A	V <sub>F</sub>	0.55		0.70		0.85		0.95		V		
Maximum DC Reverse Current T <sub>a</sub> = 25°C at Rated DC Reverse Voltage T <sub>a</sub> = 100°C	I <sub>R</sub>	0.5 5		0.3 3						mA		
Typical Junction Capacitance <sup>(1)</sup>	C <sub>j</sub>	450			350					pF		
Typical Thermal Resistance <sup>(2)</sup>	R <sub>θJA</sub>	50							°C/W			
Operating Junction Temperature Range	T <sub>j</sub>	-55 ~ +150							°C			
Storage Temperature Range	T <sub>stg</sub>	-55 ~ +150							°C			

( 1 ) Measured at 1 MHz and applied reverse voltage of 4 V D.C

( 2 ) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Fig.1 Forward Current Derating Curve

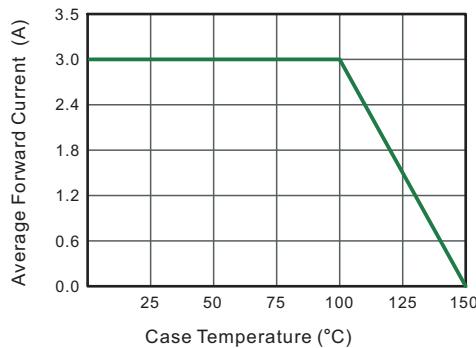


Fig.2 Typical Reverse Characteristics

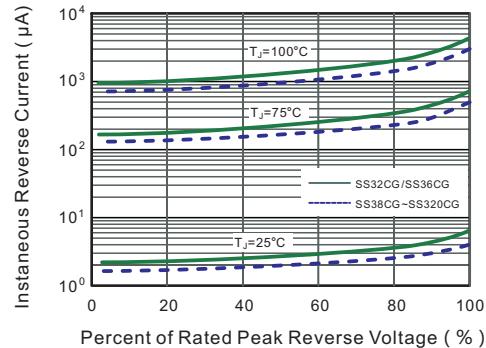


Fig.3 Typical Forward Characteristic

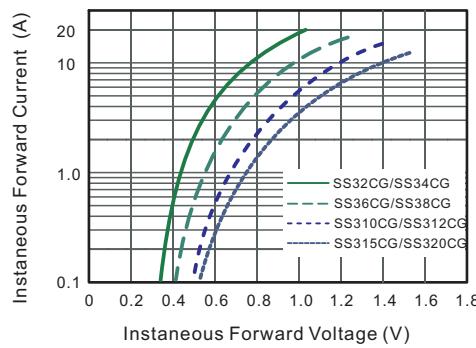


Fig.4 Typical Junction Capacitance

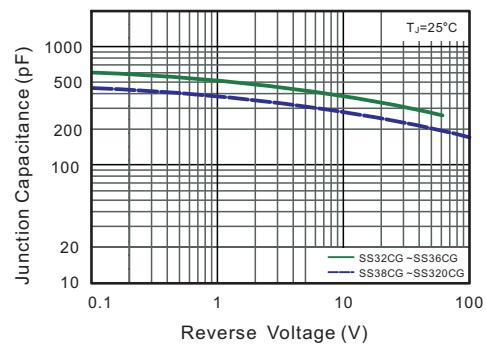


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

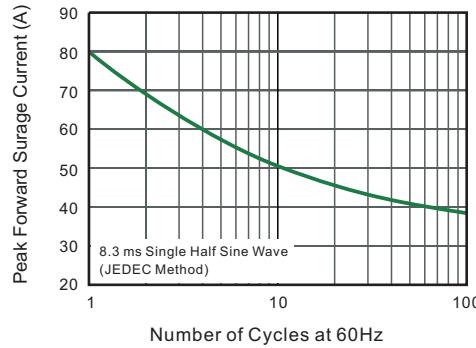
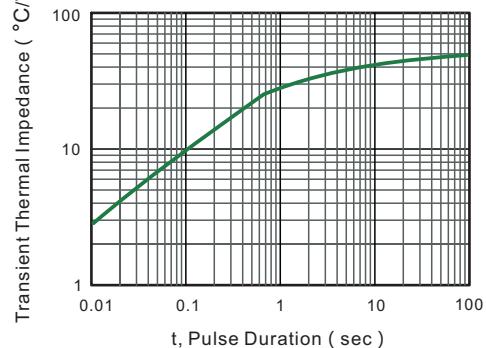


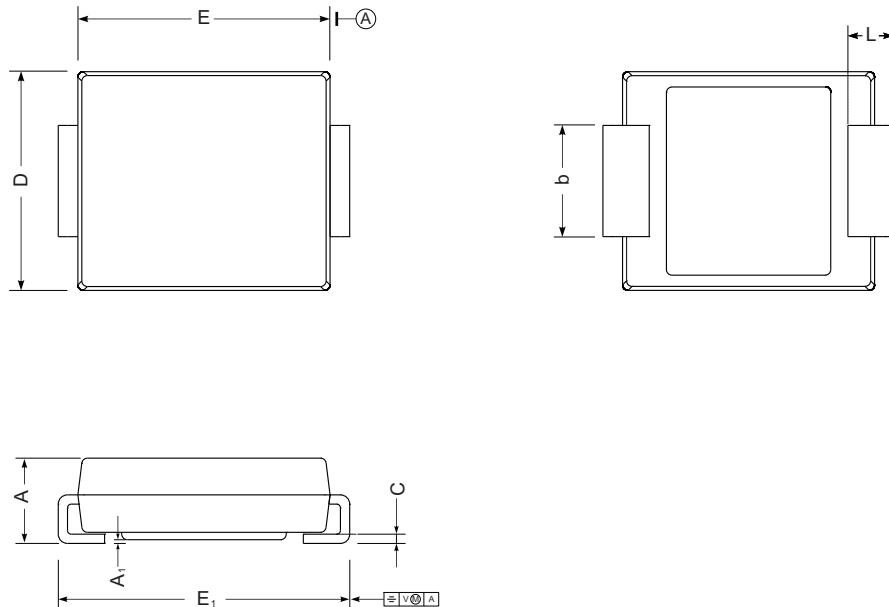
Fig.6- Typical Transient Thermal Impedance



## PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

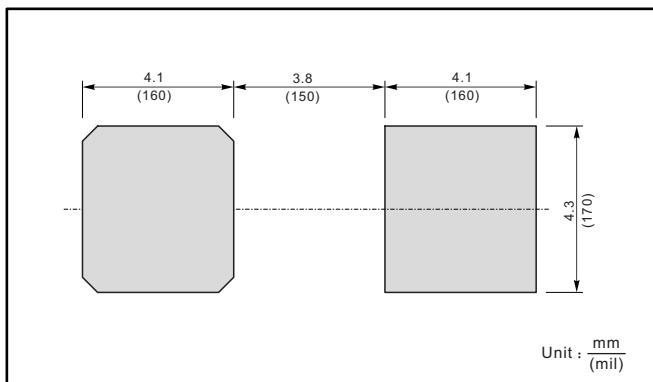
SMC



SMC mechanical data

UNIT		A	E	D	E <sub>1</sub>	A <sub>1</sub>	C	L	b
mm	max	2.62	7.0	6.2	8.0	0.21	0.31	1.6	3.25
	min	2.00	6.5	5.6	7.6	0.05	0.15	0.9	2.75
mil	max	103	276	244	315	8.3	12	63	128
	min	79	256	220	299	2.0	5.9	35	108

## The recommended mounting pad size



## Marking

Type number	Marking code
SS32CG	SS32
SS34CG	SS34
SS36CG	SS36
SS38CG	SS38
SS310CG	SS310
SS312CG	SS312
SS315CG	SS315
SS320CG	SS320

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